

Mode Mixing in Graphene p-n Junctions Investigated by Shot Noise Measurement

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Introduction

- Graphene p - n junction (PNJ)
- Bipolar quantum Hall states
- Expected shot noise at a PNJ

Device structure

- Graphene bipolar device for shot noise measurements

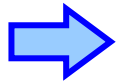
Results and discussions

- Energy relaxation along PNJs
- Beam splitter properties of PNJs

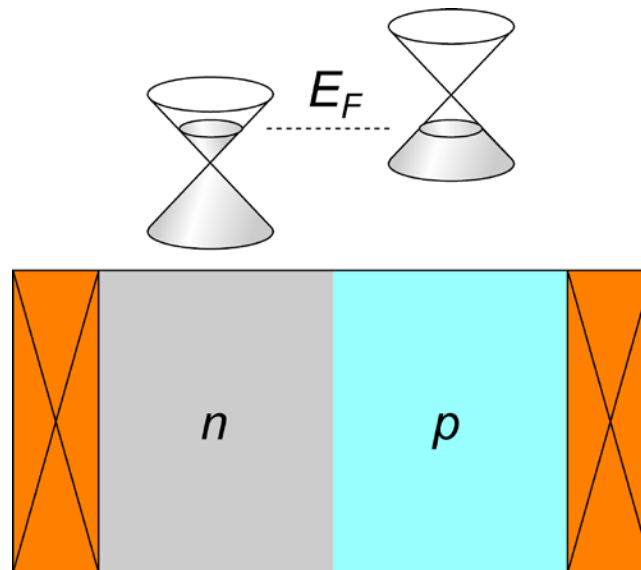
Introduction: graphene p - n junction

Graphene Linear and gapless band structure

- massless Dirac Fermion
- symmetric electron and hole properties
- adjacent electron and hole regions

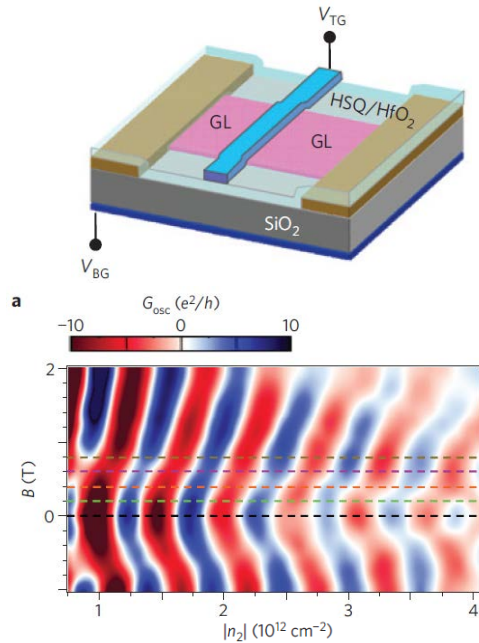


Unique system to investigate transport of Dirac Fermions across PNJs

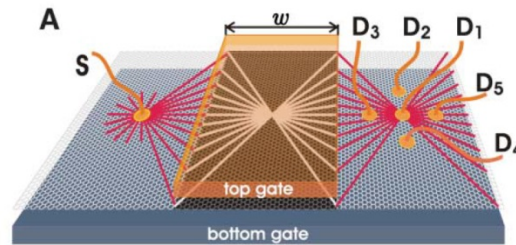


Introduction: graphene p - n junction

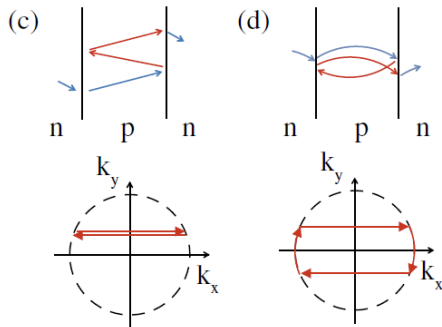
Klein tunneling



Veselago lensing

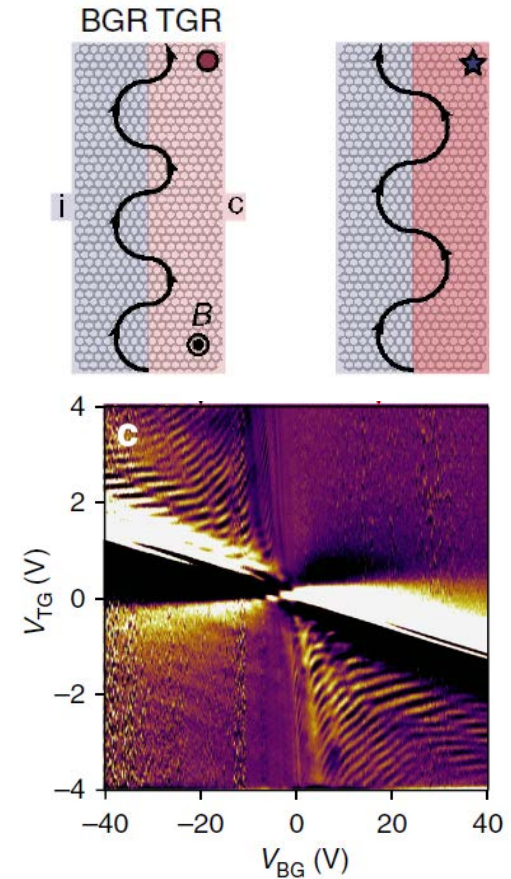


Theory:
Science 315, 1253 (2007).



Nature Phys. **5**, 222 (2009)
Nat. Commun. **4**, 2342 (2013).
Jpn. J. Appl. Phys. **52**, 110105 (2013).

Snake state



Theory:
Phys. Rev. B **81**, 241406 (2010).

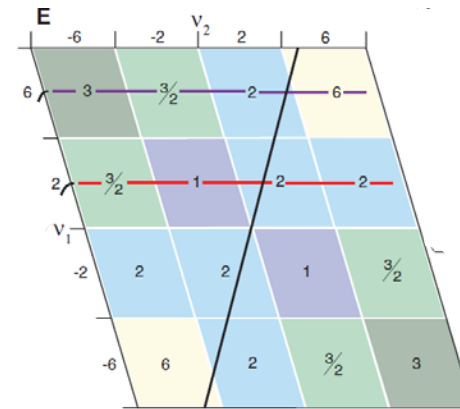
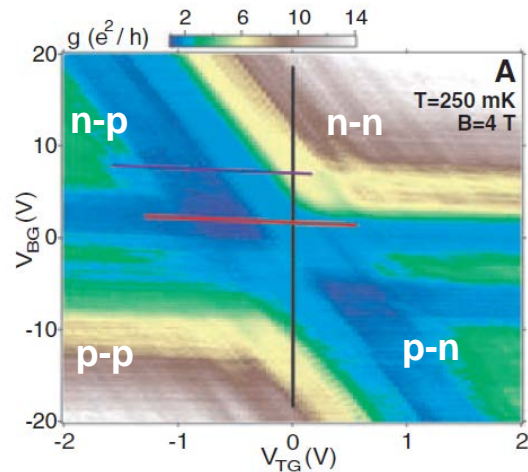
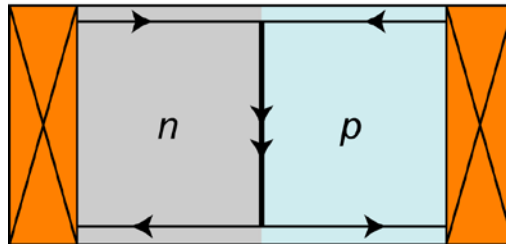
Experiment:
Phys. Rev. Lett. **107**, 046602 (2011).
Nat. Commun. **6**, 6470 (2015)
Nat. Commun. **6**, 6093 (2015).

Introduction: graphene bipolar QH state

Combination of QH physics and characteristic transport at PNJ leads to quantized conductance at unusual values.

Bipolar QH state

$$G = \frac{|v||v'|}{|v|+|v'|} \times e^2/h$$



Experiment: Science **317**, 638 (2007)

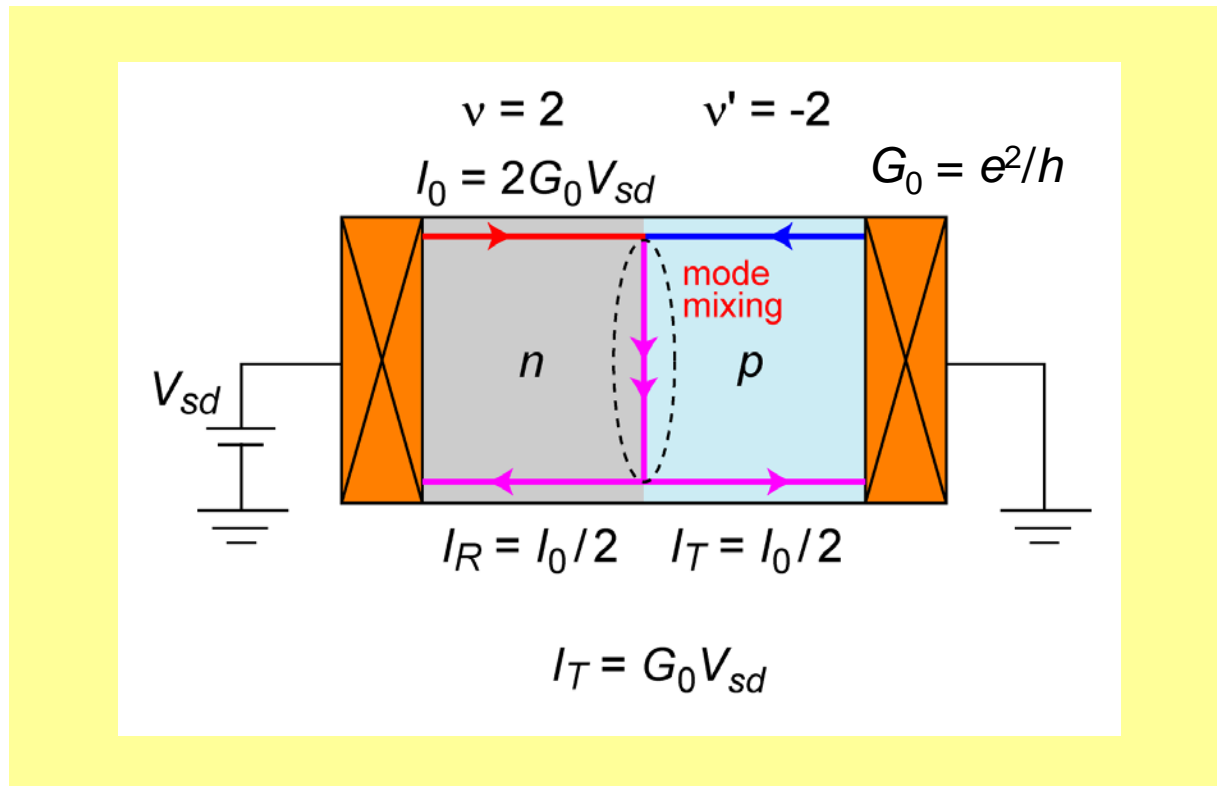
Theory: Science **317**, 641 (2007)

Introduction: graphene bipolar QH state

Combination of QH physics and characteristic transport at PNJ leads to quantized conductance at unusual values.

Bipolar QH state

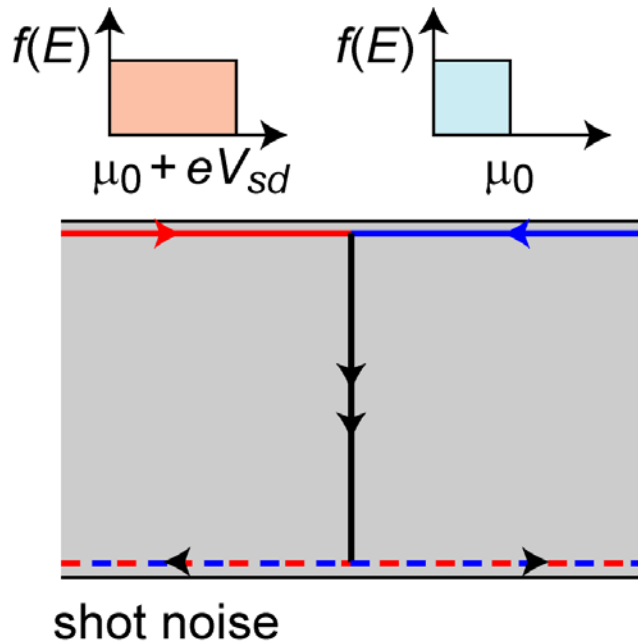
$$G = \frac{|v||v'|}{|v|+|v'|} \times e^2/h$$



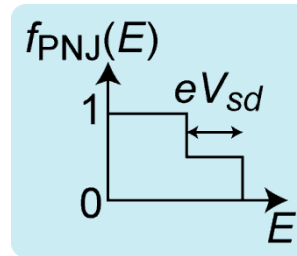
Experiment: Science **317**, 638 (2007)

Theory: Science **317**, 641 (2007)

Introduction: shot noise at graphene p - n junction



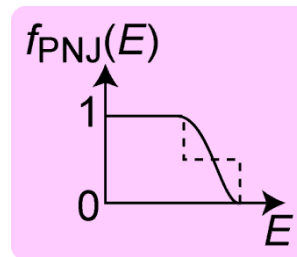
Shot noise depends on the energy distribution in the PNJ.



quasi-elastic scattering

double-step function:

$$F = 0.25$$

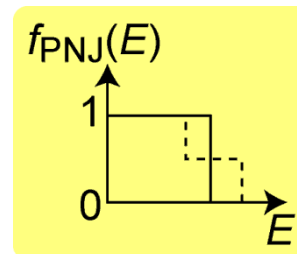


inelastic scattering in the PNJ

hot Fermi function:

$$F = 0.28$$

$$T_{eff} = eV_{sd}$$



inelastic scattering with external states

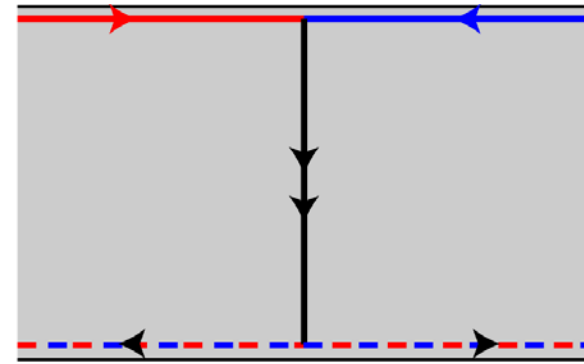
cold Fermi function:

$$F = 0$$

Note: transport measurement gives $G = e^2/h$ for all the cases.

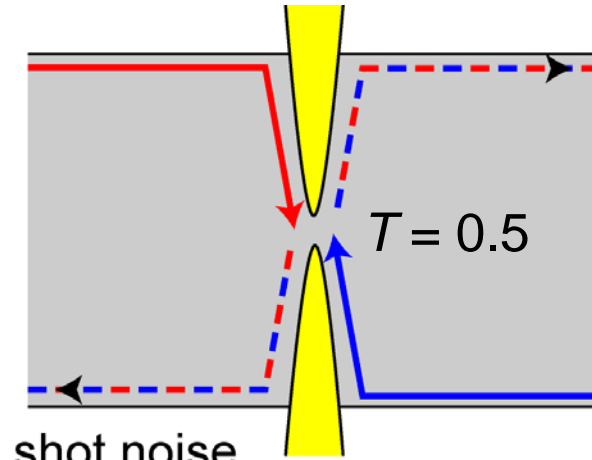
Introduction: shot noise at graphene p - n junction

PNJ in graphene



shot noise

QPC in standard semiconductor

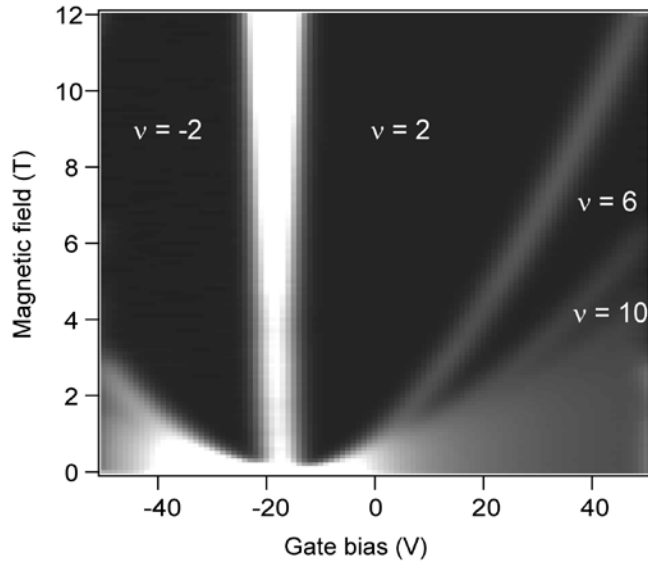


shot noise

In the case of elastic mode mixing, a PNJ can serve as a beam splitter.

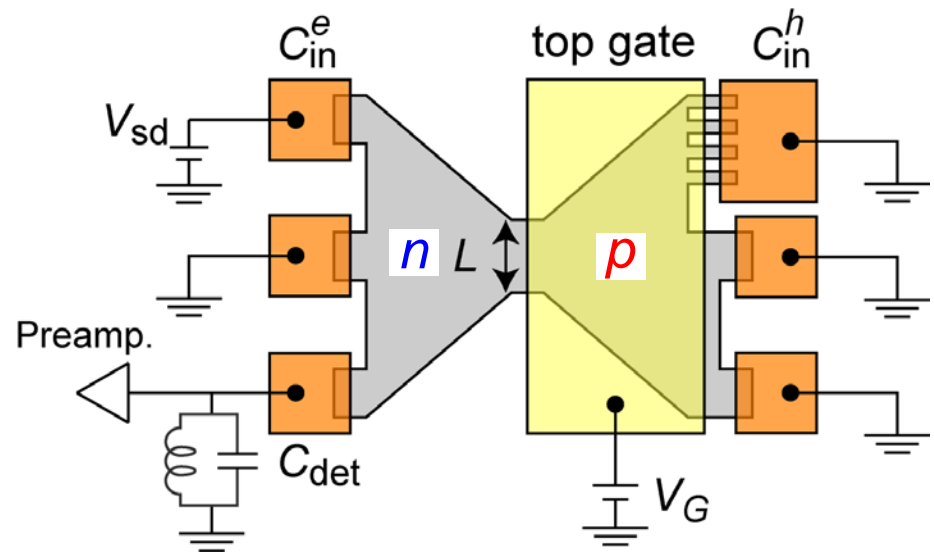
Experiment: device structure

R_{xx} in a Hall bar device



- graphene on SiC
- $n \sim 5 \times 10^{11} \text{ cm}^{-2}$

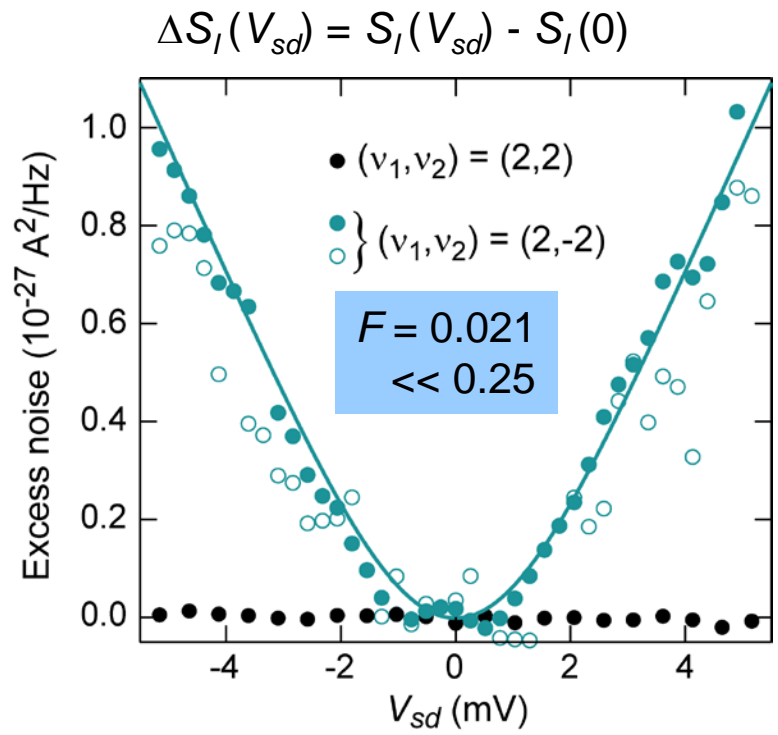
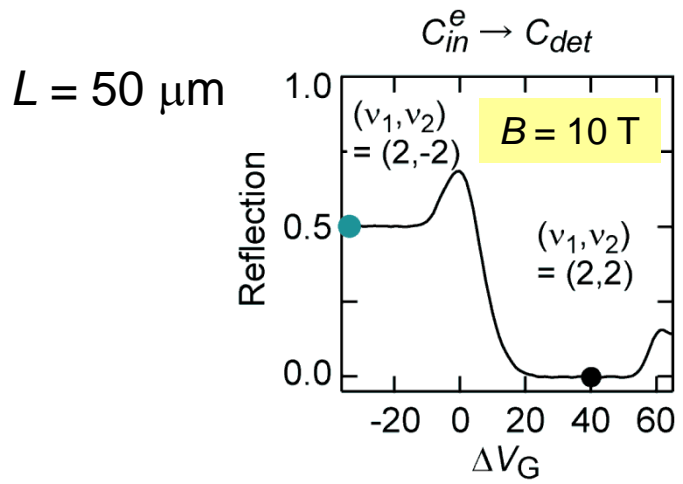
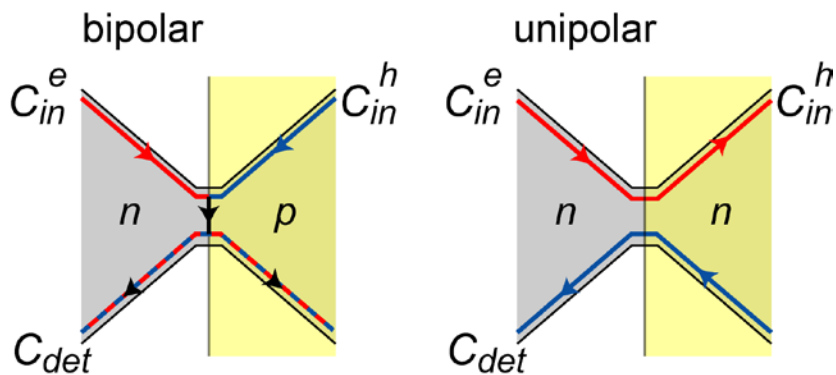
Device structure for noise measurement



$$L = 5, 10, 20, 50, 100 \text{ } \mu\text{m}$$

noise measurement at 3 MHz

Results: shot noise generated by p - n junction

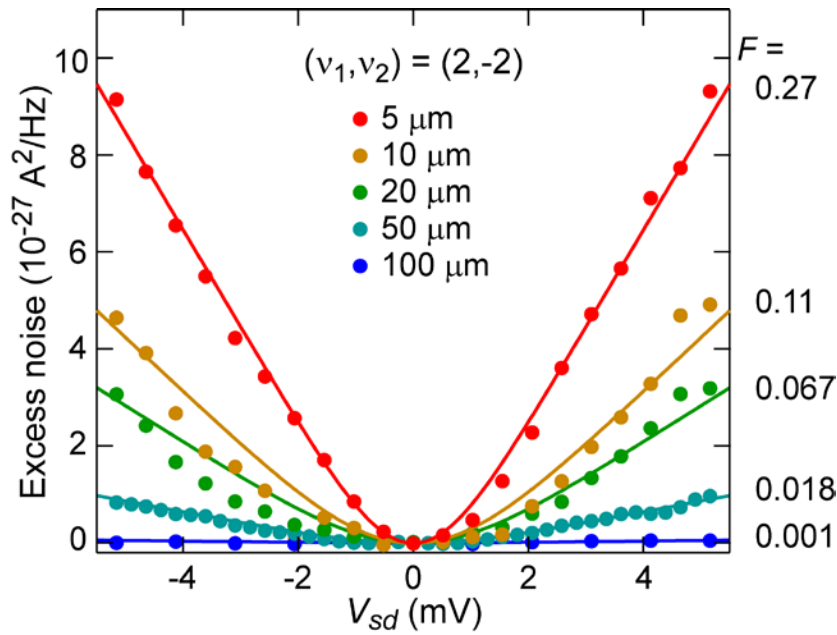


$$\Delta S_I = 2eFG_{\text{PNJ}}V_{sd} \left[\coth\left(\frac{eV_{sd}}{2k_B T}\right) - \frac{2k_B T}{eV_{sd}} \right]$$

- Shot noise is generated by the PNJ.
 - F is much smaller than that expected for double-step function.
- Energy distribution changes in the 50- μm -long PNJ.

Results: shot noise generated by p - n junction

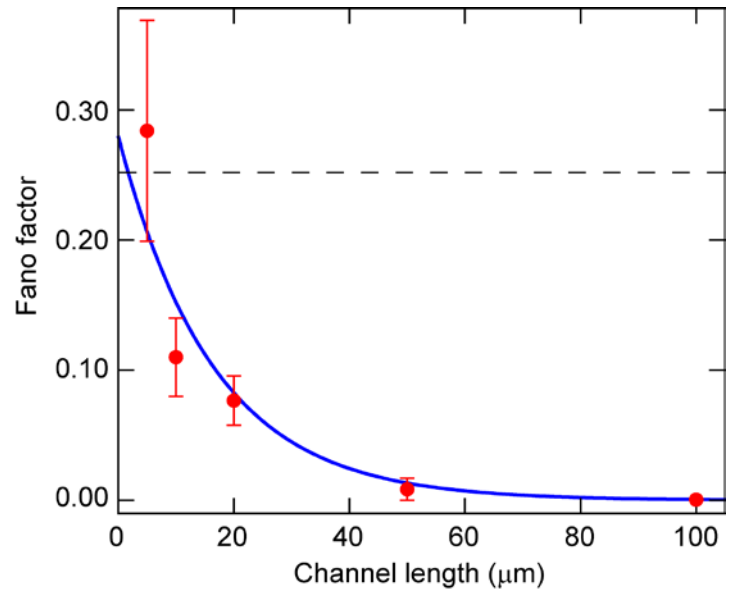
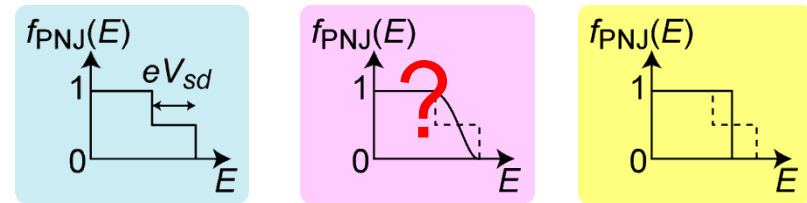
Shot noise for several L



Shot noise decreases with increasing L .

➡ Energy relaxation

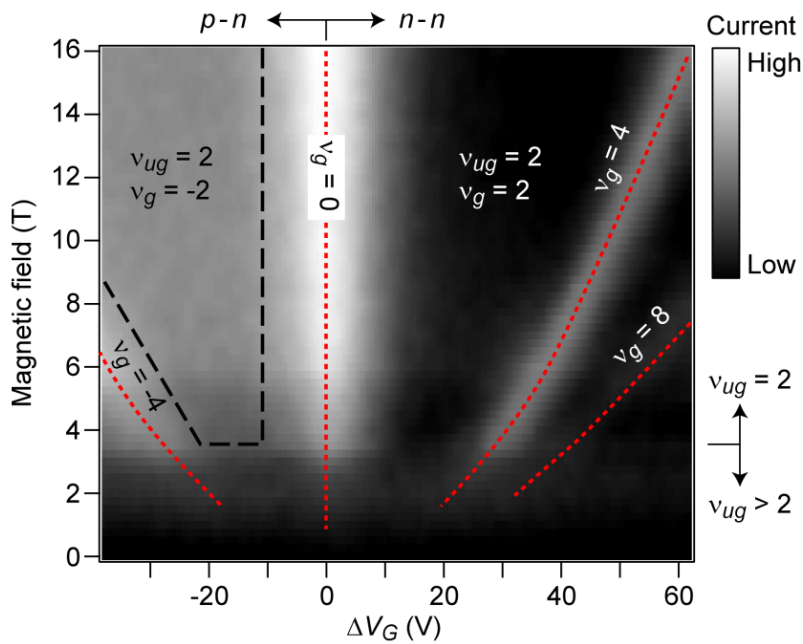
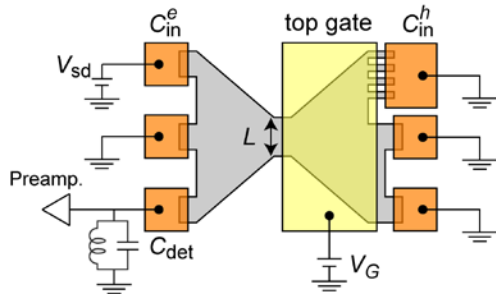
Energy loss is negligible when $L \ll L_0 = 16 \mu\text{m}$



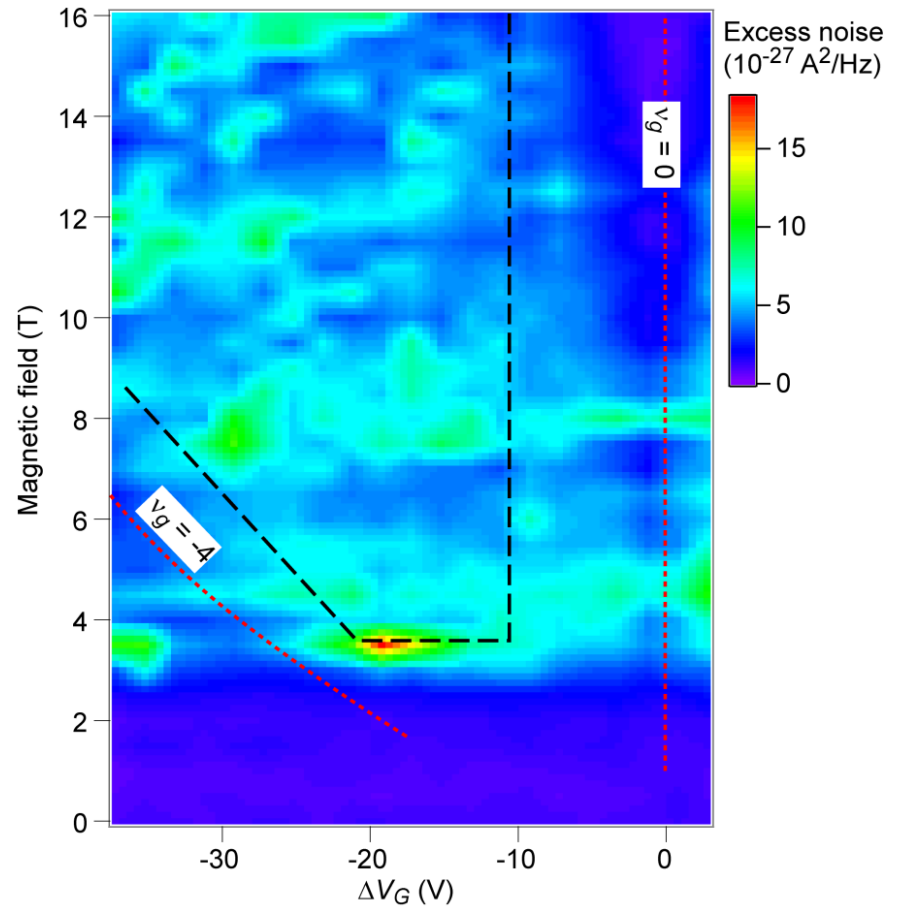
Relaxation length $L_0 = 16 \mu\text{m}$

The behavior can be explained by the coupling to cold external states.

Results: shot noise generated by p - n junction

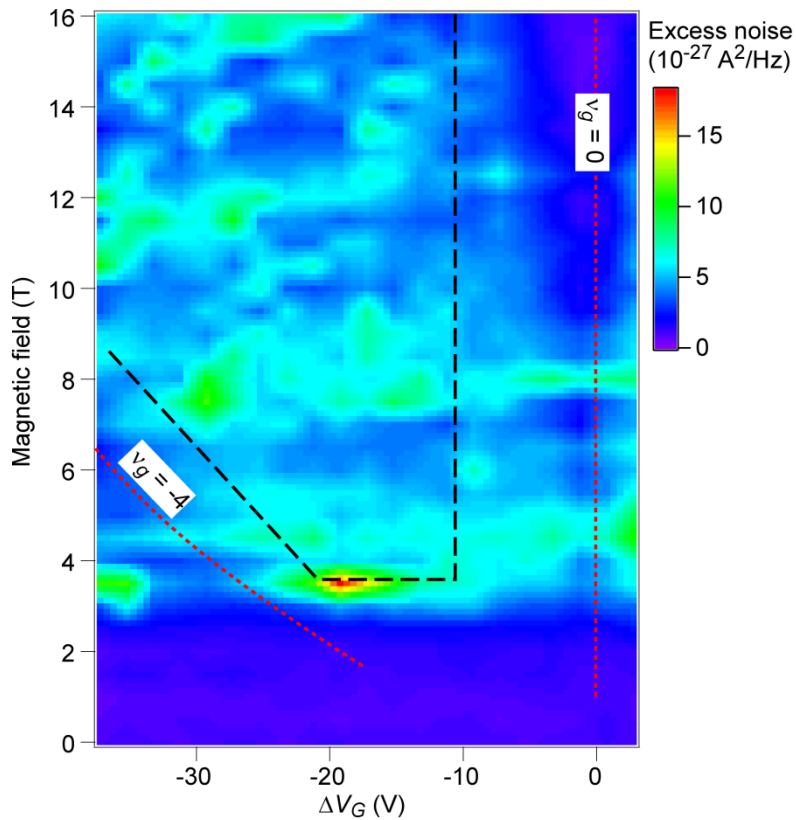


Current in the bipolar QH state is constant within 2%.



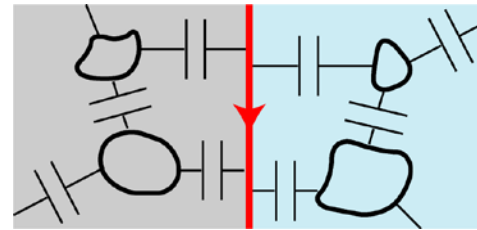
Noise in the bipolar QH state fluctuates by 50%.

Results: shot noise generated by p - n junction



Origin of the noise fluctuations

Fluctuations of the energy relaxation through interactions with localized states.

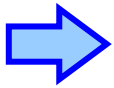


Energy level and profile of localized states depend on B and V_G .

Summary

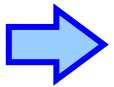
Noise measurement in graphene bipolar QH state

Noise is generated by a p-n junction.



Mode mixing at a p-n junction leads to non-equilibrium energy distribution.

Fano factor decreases with increasing PNJ length (relaxation length $16 \mu\text{m}$).



Energy distribution relaxes toward equilibrium Fermi distribution.

Beam splitter could be realized in graphene, encouraging electronic quantum optics experiments using graphene.